NSN 5962-01-370-2014

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-370-2014

Features Provided:

Burn in and electrostatic sensitive and programmed

Inclosure Material:

Ceramic

Inclosure Configuration:

Flat pack

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Memory Device Type:

Prom

Terminal Type And Quantity:

24 flat leads

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0